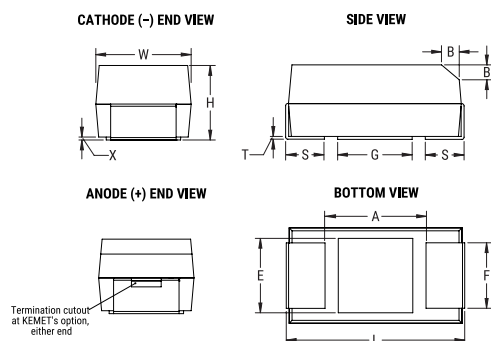


T510, Tantalum, MnO2 Tantalum, Multi-Anode, 100 uF, 20%, 25 VDC, SMD, MnO2, Molded, Large Case, Multi-Anode, LowESR, 50 mOhms, 7360, Height Max = 3.8mm



Dimensions

Footprint	7360
L	7.3mm +/-0.3mm
W	6mm +/-0.3mm
H	3.6mm +/-0.2mm
T	0.13mm REF
S	1.3mm +/-0.3mm
F	4.1mm +/-0.1mm
A	3.8mm MIN
B	0.5mm +/-0.15mm
E	3.5mm REF
G	3.5mm REF
X	0.1mm +/-0.1mm

Packaging Specifications

Weight:	500.73 mg
Packaging:	T&R, 178mm
Packaging Quantity:	500

General Information

Series:	T510
Dielectric:	MnO2 Tantalum
Style:	SMD Chip
Description:	SMD, MnO2, Molded, Large Case, Multi-Anode, LowESR
Features:	Low ESR
RoHS:	Yes
Termination:	Tin
AEC-Q200:	No
Shelf Life:	156 Weeks
MSL:	1

Specifications

Capacitance:	100 uF
Capacitance Tolerance:	20%
Voltage DC:	25 VDC (85C), 16.75 VDC (125C)
Temperature Range:	-55/+125°C
Rated Temperature:	85°C
Dissipation Factor:	8% 120Hz 20C
Failure Rate:	N/A
Resistance:	50 mOhms (100kHz)
Ripple Current:	2387 mA (rms, 100kHz 25C), 2148.3 mA (rms, 85C), 954.8 mA (rms, 125C)
Leakage Current:	25 uA (5min 20°C)